MGSF1N03LT1

Preferred Device

Power MOSFET 30 V, 2.1 A, Single N–Channel, SOT–23

These miniature surface mount MOSFETs low $R_{DS(on)}$ assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc–dc converters and power management in portable and battery–powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

Features

- Low R_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space
- Pb–Free Packages are Available

MAXIMUM RATINGS (T_{.1} = 25°C unless otherwise noted)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	30	V
Gate-to-Source Voltage	Gate-to-Source Voltage			±20	V
Continuous Drain		$T_A = 25^{\circ}C$	Ι _D	2.1	А
Current (Note 1)	State	$T_A = 85^{\circ}C$		1.5	
	$t \le 10 s$	$T_A = 25^{\circ}C$		2.8	
Power Dissipation (Note 1)	Steady State	$T_A = 25^{\circ}C$	PD	0.73	W
Continuous Drain	Steady	$T_A = 25^{\circ}C$	Ι _D	1.6	А
Current (Note 2)	State	$T_A = 85^{\circ}C$		1.1	
Power Dissipation (Note 2)		$T_A = 25^{\circ}C$	P _D	0.42	W
Pulsed Drain Current	t _p = 10 μs		I _{DM}	6.0	А
ESD Capability (Note 3)	C = 100 pF, RS = 1500 Ω		ESD	125	V
Operating Junction and Storage Temperature			T _J , T _{STG}	-55 to 150	°C
Source Current (Body Diode)		I _S	2.1	А	
Lead Temperature for Soldering Purposes (1/8" from case for 10 sec)			ΤL	260	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	170	°C/W
Junction-to-Ambient - t < 10 s (Note 1)	R_{\thetaJA}	100	
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	300	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using 1 in sq pad size.

- 2. Surface-mounted on FR4 board using the minimum recommended pad size.
- 3. ESD Rating Information: HBM Class 0.

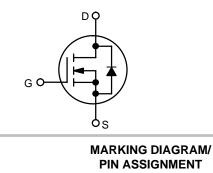


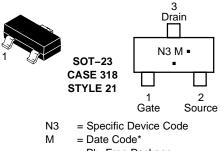
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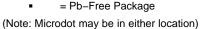
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V _{(BR)DSS}	R _{DS(on)} TYP	I _D MAX
30 V	80 mΩ @ 10 V	2.1 A
	125 mΩ @ 4.5 V	









*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MGSF1N03LT1	SOT-23	3000/Tape & Reel
MGSF1N03LT1G	SOT-23 Pb-Free	3000/Tape & Reel
MGSF1N03LT3	SOT-23	10,000/Tape & Reel
MGSF1N03LT3G	SOT-23 (Pb-Free)	10,000/Tape & Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

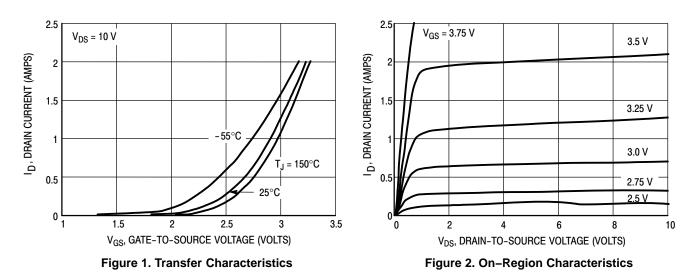
Preferred devices are recommended choices for future use and best overall value.

MGSF1N03LT1

Char	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						•
Drain–to–Source Breakdown Voltage ($V_{GS} = 0 \text{ Vdc}, I_D = 10 \mu \text{Adc}$)		V _{(BR)DSS}	30	-	-	Vdc
Zero Gate Voltage Drain Current ($V_{DS} = 30 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}$) ($V_{DS} = 30 \text{ Vdc}, V_{GS} = 0 \text{ Vdc}, T_J = 125^{\circ}\text{C}$)		I _{DSS}	-		1.0 10	μAdc
Gate-Body Leakage Current (V _{GS}	I _{GSS}	_	-	±100	nAdc	
ON CHARACTERISTICS (Note 4)						
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = 250 \ \mu Adc)$		V _{GS(th)}	1.0	1.7	2.4	Vdc
Static Drain-to-Source On-Resistance $(V_{GS} = 10 \text{ Vdc}, I_D = 1.2 \text{ Adc})$ $(V_{GS} = 4.5 \text{ Vdc}, I_D = 1.0 \text{ Adc})$		r _{DS(on)}	-	0.08 0.125	0.10 0.145	Ω
DYNAMIC CHARACTERISTICS						
Input Capacitance	(V _{DS} = 5.0 Vdc)	C _{iss}	_	140	-	pF
Output Capacitance	(V _{DS} = 5.0 Vdc)	C _{oss}	_	100	-	
Transfer Capacitance	(V _{DG} = 5.0 Vdc)	C _{rss}	-	40	-	
SWITCHING CHARACTERISTICS (Note 5)					
Turn-On Delay Time		t _{d(on)}	-	2.5	-	ns
Rise Time	(V _{DD} = 15 Vdc, I _D = 1.0 Adc,	t _r	-	1.0	-	
Turn-Off Delay Time	R _L = 50 Ω)	t _{d(off)}	-	16	-	
Fall Time	7	t _f	-	8.0	-	1
Gate Charge (See Figure 6)		QT	_	6000	-	рС
SOURCE-DRAIN DIODE CHARAC	TERISTICS	-		·	•	•
Continuous Current		۱ _S	-	-	0.6	А
Pulsed Current		I _{SM}	_	-	0.75	
Forward Voltage (Note 5)		V _{SD}	_	0.8	_	V

4. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

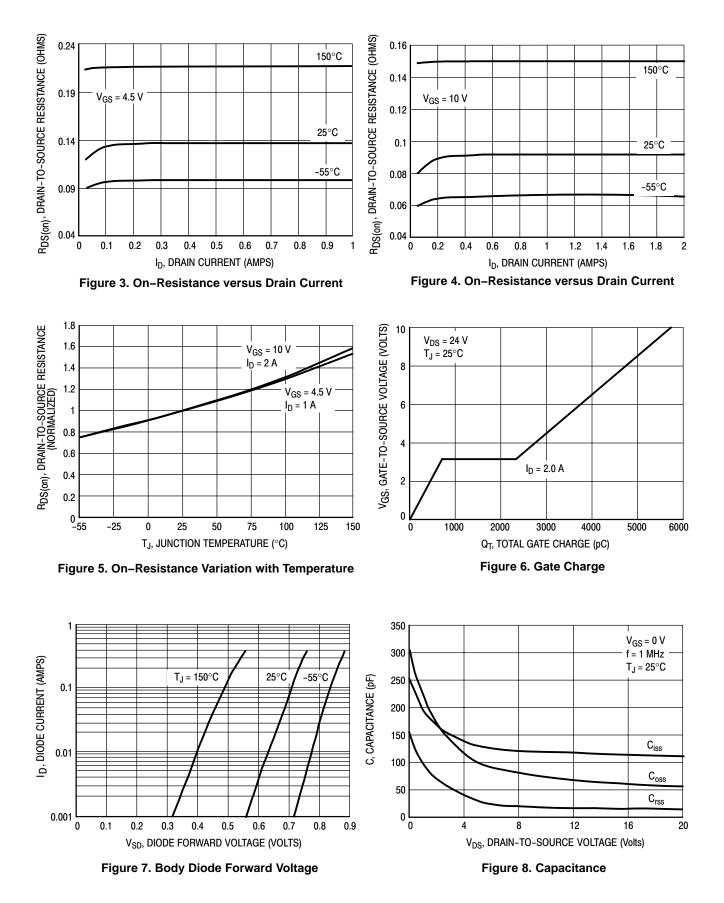
5. Switching characteristics are independent of operating junction temperature.



TYPICAL ELECTRICAL CHARACTERISTICS

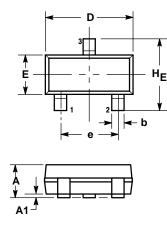
MGSF1N03LT1

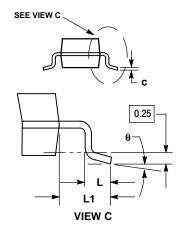
TYPICAL ELECTRICAL CHARACTERISTICS



PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN**





NOTES DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

CONTROLLING DIMENSION: INCH.
MAXIMUM LEAD THICKNESS INCLUDES

LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF

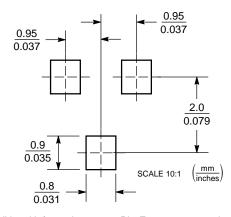
BASE MATERIAL. 318-01 THRU -07 AND -09 OBSOLETE,

NEW STANDARD 318-08.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
С	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 21: PIN 1. GATE SOURCE 2 DRAIN 3.

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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